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## **Clean Version of Pending Claims**

METHOD FOR ATTACHING A SEMICONDUCTOR DIE TO A SUBSTRATE Applicant: Edward A. Schrock et al.

Serial No.: 09/649,827

Claims 34-63 as of June 6, 2002 (date of response to final office action filed).

A method of attaching a semiconductor die to an organic support structure, contorising: 34.) selecting a two-sided adhesive tape having at least one adhesive, wherein the adhesive tape has a low lamination temperature;

affixing a first side of the two-sided adhesive tape to a surface of the organic support structure; and

affixing a face of the semiconductor die to a second side of the adhesive tape.

- 35.) A method of attaching a semiconductor die to an organic support structure, comprising: affixing a first side of a two-sided adhesive tape to a surface of the organic support structure, wherein the adhesive tape is a hybrid material including a first material having a high glass transition temperature and a second material having a low glass transition temperature; and affixing a face of the semiconductor die to a second side of the adhesive tape.
- 36.) A method of attaching a semiconductor die to an organic support structure, comprising: affixing a first side of a two-sided adhesive tape to a surface of the organic support structure, wherein the adhesive tape is a hybrid material including thermoplastic and thermoset material, and the thermoset component has a glass transition temperature of approximately 30 degrees C; and

affixing a face of the semiconductor die to a second side of the adhesive tape.



37.) A method of attaching a semiconductor die to an organic support structure, comprising: affixing a first side of a two-sided adhesive tape to a surface of the organic support structure, wherein the adhesive tape has a lamination temperature of less than or equal to approximately 100 degrees C; and

affixing a face of the semiconductor die to a second side of the adhesive tape.

- 38.) A method of attaching a semiconductor die to an organic support structure, comprising: affixing a first side of a two-sided adhesive tape to a surface of the organic support structure, each side of the tape having an adhesive layer, wherein the adhesive tape has a lamination temperature of less than or equal to approximately 100 degrees C, each adhesive layer having a thickness of .0005 inches, and the carrier layer having a thickness of .002 inches; and affixing a face of the semiconductor die to a second side of the adhesive tape.
- 39.) (Thrice Amended) A method of attaching a semiconductor die to an organic support structure, comprising:

affixing a first side of a two-sided adhesive tape to a surface of the organic support structure, wherein adhesive of the adhesive tape comprises a hybrid material of thermoplastic and thermosetting adhesive;

elevating the temperature to 100 degrees C to activate the first side of the adhesive tape; applying pressure to the tape and organic support structure to laminate the adhesive tape to the organic support structure;

affixing a face of the semiconductor die to a second side of the adhesive tape; elevating the temperature of the tape to activate the second side of the adhesive tape; and applying pressure to the die and organic support structure to laminate the adhesive tape to the die.



- 40.) The method of claim 39 further comprising electrically connecting a plurality of bond pads on the die face with a plurality of lead connections on the organic support structure.
- 41.) The method of claim 40 wherein electrically connecting the bond pads to the lead connections comprises wire bonding bond wires to the bond pads and the lead connections.
- 42.) The method of claim 41 further comprising forming an encapsulating material around portions of the die and organic support structure.
- 43.) The method of claim 42 wherein the encapsulating material encapsulates the bond pads, bond wires, lead connections, and a portion of the die face and support structure.
- 44.) (Thrice Amended) A method of attaching a semiconductor die to an organic support structure, comprising:

affixing a first side of a two-sided adhesive tape to a surface of the organic support structure, wherein adhesive of the adhesive tape comprises a hybrid material of thermoplastic and thermosetting adhesive;

elevating the temperature of the tape to activate the first side of the adhesive tape; applying pressure to the tape and organic support structure to laminate the adhesive tape to the organic support structure, wherein elevating the temperature and applying pressure occurs for 100ms;

affixing a face of the semiconductor die to a second side of the adhesive tape;
elevating the temperature of the tape to activate the second side of the adhesive tape;
applying pressure to the die and organic support structure to laminate the adhesive tape to
the die;

wire bonding bond wires to a plurality of bond pads on the die face with a plurality of



lead connections on the organic support structure;

applying an encapsulating material over the bond pads, bond wires, lead connections, and a portion of the die face and support structure.

- 45.) The method of claim 44 wherein the encapsulating material comprises a curable glob-top formed by dispensing a viscous curable material.
- 46.) The method of claim 45 further comprising curing the encapsulating material.
- 47.) The method of claim 46 further comprising inverting the organic support structure and applying a second curable glob-top to a perimeter of a back side of the semiconductor die.
- 48.) The method of claim 47 further comprising curing the die and the organic support structure.
- 49.) The method of claim 48 further comprising trimming the organic support structure to form a BGA package.
- 50.) The method of claim 49 further comprising electrically interconnecting the BGA package to a receiving component.
- 51.) A method for fabricating a semiconductor package comprising:

  providing a semiconductor die having a face and a plurality of bond pads;

  providing an organic support structure comprising a die attach area and a plurality of lead connections;

providing a two-sided adhesive tape intermediate the die and the organic support structure



to bond the die thereto, wherein the adhesive tape has a lamination temperature of about ambient temperature; and

attaching a first side of the adhesive tape to the die attach area of the organic support structure and a second side of the adhesive tape to the die face.

- 52.) The method of claim 51 further comprising applying low heat to laminate the tape to the die and the organic support structure.
- 53.) The method of claim 52 further comprising applying pressure to laminate the tape to the die and the organic support structure.
- 54.) The method of claim 53 further comprising electrically connecting the bond pads to the lead connections.
- 55.) The method of claim 54 wherein the electrical connection comprises connecting a series of bond wires to the bond pads and to the lead connections.
- 56.) The method of claim 55 further comprising applying a viscous material to cover the bond pads, lead connections, bond wires, and a portion of the organic support structure.
- 57.) The method of claim 56 wherein the viscous material is a curable glob-top.
- 58.) The method of claim 34 further comprising applying pressure and 100 degrees C to the tape for 100ms and laminating the tape to the support structure.



- 59.) The method of claim 34 further comprising laminating the tape to the organic support structure at ambient temperature.
- 60.) The method of claim 34 further comprising laminating the tape to the organic support structure at 100 degrees C or less.
- 61.) The method of claim 34 wherein the adhesive tape comprises Carboxyl Terminated Acrylonitrile Butadiene modified epoxy resin.
- 62.) The method of claim 34 wherein the adhesive tape comprises Carboxyl Terminated Acrylonitrile Butadiene modified epoxy resin formed into layers approximately .0005 inches in thickness.
- 63.) The method of claim 34 wherein the adhesive tape includes a carrier layer, the adhesive tape has a lamination temperature of less than or equal to approximately 100 degrees C, each adhesive layer has a thickness of .0005 inches, and the carrier layer having a thickness of .002 inches.